## Thermally-Enhanced High Power RF LDMOS FET 100 W, 28 V, 2490 - 2690 MHz

## Description

The PXAC261002FC is a 100-watt LDMOS FET with an asymmetric design intended for use in multi-standard cellular power amplifier applications in the 2496 to 2690 MHz frequency band. Features include dual-path design, high gain and a thermally-enhanced package with earless flanges. Manufactured with Infineon's advanced LDMOS process, this device provides excellent thermal performance and superior reliability.


PXAC261002FC


Package H-37248-4

## Features

- Broadband internal input and output matching
- Asymmetric design
- Main: P1dB = 40 W Typ
- Peak: P1dB = 70 W Typ
- Typical Pulsed CW performance, $2590 \mathrm{MHz}, 26 \mathrm{~V}$, $160 \mu \mathrm{~s}, 10 \%$ duty cycle, Doherty Configuration
- Output power at $\mathrm{P}_{1 \mathrm{~dB}}=46.5 \mathrm{dBm}$
- Output power at $P_{3 \mathrm{~dB}}=50.1 \mathrm{dBm}$
- Capable of handling 10:1 VSWR @28 V, 100 W (CW) output power
- Integrated ESD protection : Human Body Model, Class 1C (per JESD22-A114)
- Low thermal resistance
- Pb-free and RoHS compliant


## RF Characteristics

Two-carrier WCDMA Specifications (tested in Infineon production Doherty test fixture)
$\mathrm{V}_{\mathrm{DD}}=26 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=210 \mathrm{~mA}, \mathrm{P}_{\mathrm{OUT}}=18 \mathrm{~W}$ avg, $\mathrm{V}_{\mathrm{GS} 2}=1.4 \mathrm{~V}, f_{1}=2550 \mathrm{MHz}, f_{2}=2590 \mathrm{MHz}, 3 \mathrm{GPP}$ signal, 3.84 MHz channel bandwidth, 8 dB peak/average @ 0.01\% CCDF

| Characteristic | Symbol | Min | Typ | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Gain | $G_{p s}$ | 14.1 | 15.1 | - | dB |
| Drain Efficiency | $\eta_{\mathrm{D}}$ | 46 | 49 | - | $\%$ |
| Intermodulation Distortion | IMD | - | -22 | -21 | dBc |
| Output PAR at $0.01 \%$ probability on CCDF | OPAR | 7.5 | - | - | dB |

(one-carrier WCDMA, $2585 \mathrm{MHz}, 10 \mathrm{~dB}$ PAR)

All published data at $T_{\text {CASE }}=25^{\circ} \mathrm{C}$ unless otherwise indicated
ESD: Electrostatic discharge sensitive device—observe handling precautions!

PXAC261002FC

DC Characteristics (each side)

| Characteristic | Conditions | Symbol | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Drain-Source Breakdown Voltage | $\mathrm{V}_{\mathrm{GS}}=0 \mathrm{~V}, \mathrm{I}_{\mathrm{DS}}=10 \mathrm{~mA}$ | V (BR)DSS | 65 | - | - | V |
| Drain Leakage Current | $\mathrm{V}_{\mathrm{DS}}=28 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | Idss | - | - | 1 | $\mu \mathrm{A}$ |
|  | $\mathrm{V}_{\mathrm{DS}}=63 \mathrm{~V}, \mathrm{VGS}=0 \mathrm{~V}$ | IdSs | - | - | 10 | $\mu \mathrm{A}$ |
| Gate Leakage Current | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0 \mathrm{~V}$ | IGSS | - | - | 1 | $\mu \mathrm{A}$ |
| On-State Resistance | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.1 \mathrm{~V}$ | $\mathrm{R}_{\text {DS(on) }}$ | - | 0.3 | - | $\Omega$ |
|  | $\mathrm{V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{~V}_{\mathrm{DS}}=0.1 \mathrm{~V}$ | $\mathrm{R}_{\mathrm{DS} \text { (on) }}$ | - | 0.16 | - | $\Omega$ |
| Operating Gate Voltage (main) | $\mathrm{V}_{\mathrm{DS}}=26 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=210 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{GS}}$ | 2.1 | 2.6 | 3.1 | V |
| (peak) | $\mathrm{V}_{\mathrm{DS}}=26 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=0 \mathrm{~mA}$ | $\mathrm{V}_{\mathrm{GS}}$ | 0.9 | 1.4 | 1.9 | V |

## Maximum Ratings

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Drain-Source Voltage | $\mathrm{V}_{\mathrm{DSS}}$ | 65 | V |
| Gate-Source Voltage | $\mathrm{V}_{\mathrm{GS}}$ | -6 to +10 | V |
| Operating Voltage | $\mathrm{V}_{\mathrm{DD}}$ | 0 to +32 | V |
| Junction Temperature | $\mathrm{T}_{J}$ | 225 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature Range | $\mathrm{T}_{\text {STG }}$ | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Thermal Resistance (Doherty, $\left.\mathrm{T}_{\mathrm{CASE}}=70^{\circ} \mathrm{C}, 100 \mathrm{~W} \mathrm{CW}\right)$ | $\mathrm{R}_{\theta \mathrm{JC}}$ | 0.6 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## Ordering Information

| Type and Version | Order Code | Package and Description | Shipping |
| :--- | :--- | :--- | :--- |
| PXAC261002FC V1 R0 | PXAC261002FCV1R0XTMA1 | H-37248-4, open-cavity, <br> push-pull, earless flange | Tape \& Reel, 50 pcs |
| PXAC261002FC V1 R250 | PXAC261002FC V1R250XTMA1 | H-37248-4, earless flange <br> push-pull, earless flange | Tape \& Reel, 250 pcs |

PXAC261002FC

Typical Performance (data taken in a production Doherty test fixture)





## Typical Performance (cont.)



## Load Pull Performance

Main Side Load Pull Performance - Pulsed CW signal: $160 \mu \mathrm{~s}, 10 \%$ duty cycle, $\mathrm{V}_{\mathrm{DD}}=28 \mathrm{~V}, \mathrm{I}_{\mathrm{DQ}}=240 \mathrm{~mA}$

|  |  | $\mathbf{P}_{1 \mathrm{~dB}}$ |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Max Output Power |  |  |  |  | Max PAE |  |  |  |  |
| Freq [MHz] | $\begin{gathered} \text { Zs } \\ {[\Omega]} \end{gathered}$ | $\begin{gathered} \mathrm{Zl} \\ {[\Omega]} \end{gathered}$ | Gain <br> [dB] | POUT [dBm] | POUT <br> [W] | $\begin{aligned} & \text { PAE } \\ & \text { [\%] } \end{aligned}$ | $\begin{gathered} \mathrm{Zl} \\ {[\Omega]} \end{gathered}$ | Gain <br> [dB] | POUT [dBm] | POUT <br> [W] | $\begin{aligned} & \text { PAE } \\ & \text { [\%] } \end{aligned}$ |
| 2540 | 13.3-j23.8 | 5.7-j10.9 | 16.8 | 46.58 | 45 | 50.3 | 10.9-j7.1 | 19.1 | 45.1 | 32 | 59.5 |
| 2590 | 16.5-j22.0 | 5.9-j11.5 | 16.7 | 46.44 | 44 | 50.3 | 9.7-j7.6 | 18.7 | 45.3 | 34 | 58.5 |
| 2640 | 21-j24.7 | 6.4-j11.5 | 16.8 | 46.35 | 43 | 50.0 | $10-\mathrm{j} 6.2$ | 19.1 | 44.9 | 31 | 58.0 |

Peak Side Load Pull Performance - Pulsed CW signal: $160 \mu \mathrm{~s}, 10 \%$ duty cycle, $28 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS} 1}=1.4 \mathrm{~V}$

|  |  | $\mathbf{P}_{1 \mathrm{~dB}}$ |  |  |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Max Output Power |  |  |  |  | Max PAE |  |  |  |  |
| Freq [MHz] | $\begin{gathered} \mathrm{Zs} \\ {[\Omega]} \end{gathered}$ | $\begin{gathered} \mathrm{Zl} \\ {[\Omega]} \\ \hline \end{gathered}$ | Gain <br> [dB] | POUT [dBm] | POUT <br> [W] | $\begin{aligned} & \hline \text { PAE } \\ & \text { [\%] } \end{aligned}$ | $\begin{gathered} \mathrm{Zl} \\ {[\Omega]} \\ \hline \end{gathered}$ | Gain <br> [dB] | POUT [dBm] | Pout <br> [W] | $\begin{aligned} & \text { PAE } \\ & \text { [\%] } \end{aligned}$ |
| 2540 | 3.8-j12.1 | 11.8-j7.3 | 13.0 | 50 | 100 | 53.5 | 5.2-j5.3 | 14.4 | 48.4 | 69 | 63.4 |
| 2590 | 5.2-j12.8 | 13-j5.4 | 12.8 | 50 | 100 | 53.4 | 5.7-j5.6 | 14.2 | 48.5 | 71 | 62.2 |
| 2640 | 5.8-j13.3 | 14-j3.9 | 12.8 | 49.9 | 98 | 52.9 | 6.6-j6 | 14.2 | 48.4 | 69 | 61.0 |

PXAC261002FC

Reference Circuit, 2545 - 2595 MHz


Reference circuit assembly diagram (not to scale)

PXAC261002FC

## Reference Circuit (cont.)

Reference Circuit Assembly

| DUT | PXAC261002FC V1 |
| :--- | :--- |
| Test Fixture Part No. | LTA/PXAC261002FC V1 |
| PCB | Rogers 4350, $0.508 \mathrm{~mm}\left[0.020\right.$ "] thick, 2 oz. copper, $\varepsilon_{r}=3.66, f=2545-2595 \mathrm{MHz}$ |

Find Gerber files for this test fixture on the Infineon Web site at http://www.infineon.com/rfpower
Components Information

| Component | Description | Suggested Manufacturer | P/N |
| :--- | :--- | :--- | :--- |
| Input |  |  |  |
| C101, C106 | Capacitor, $10 \mu \mathrm{~F}$ | Taiyo Yuden | UMK325C7106MM-T |
| C102 | Capacitor, 18 pF | ATC | ATC800A180JT250T |
| C103 | Capacitor, 1.6 pF | ATC | ATC800A1R6CT250T |
| C104 | Capacitor, 0.6 pF | ATC | ATC800A0R6CT250T |
| C105, C107 | Capacitor, 12 pF | ATC | ATC800A120JT250T |
| R101, R103 | Resistor, 10 ohm | Panasonic Electronic Components | ERJ-3GEYJ100V |
| R102 | Resistor, 50 ohm | Anaren | C16A50Z4 |
| S1 | Hybrid coupler | Anaren | X3C26P1-03S |
| Output |  |  |  |
| C201, C202 | Capacitor, 12 pF | ATC | ATC800A120KT250T |
| C203, C205, C208, <br> C210 | Capacitor, $10 \mu \mathrm{~F}$ | Taiyo Yuden | UMK325C7106MM-T |
| C204, C209 | Capacitor, $220 \mu \mathrm{~F}$ | Panasonic Electronic Components | EEE-FP1V221A |
| C206 | Capacitor, 0.5 pF | ATC | ATC800A0R5CT250T |
| C207 | Capacitor, 0.6 pF | ATC | ATC800A0R6CT250T |
| C211 | Capacitor, 12 pF | ATC | ATC800A120JT250T |
| C212 | Capacitor, 0.4 pF | ATC | ATC800A0R4CT250T |
| C213 | Capacitor, 3.9 pF | ATC | ATC800A3R9CT250T |

Pinout Diagram (top view)


Lead connections for PXAC261002FC

## Package Outline Specifications



Find the latest and most complete information about products and packaging at the Infineon Internet page http://www.infineon.com/rfpower

Revision History

| Revision | Date | Data Sheet Type | Page | Subjects (major changes since last revision) |
| :--- | :--- | :--- | :--- | :--- |
| 01 | $2013-11-01$ | Advance | All | Data Sheet reflects advance specification for product development |
| 02 | $2014-01-28$ | Production | All <br> All | Data Sheet reflects released product specification <br> Revised all data and includes final specs, typical performance graphs, loadpull, reference circuit |
| 03 | $2014-03-26$ | Production | 1 | Corrected frequency range. Removed "doherty" from second feature. Updated feature 2. |
| 03.1 | $2014-04-04$ | Production | 1 | Removed bullet point 4 (extra lines) from Features section. |
| 03.2 | $2016-06-07$ | Production | 1 | Added OPAR to RF table. |
| 03.3 | $2016-06-15$ | Production | 1 | Adjust OPAR information. |

## We Listen to Your Comments

Any information within this document that you feel is wrong, unclear or missing at all?
Your feedback will help us to continuously improve the quality of this document.
Please send your proposal (including a reference to this document) to:
highpowerRF@infineon.com
To request other information, contact us at: +1 8774653667 (1-877-GO-LDMOS) USA or +1 4087760600 International


## Edition 2016-06-15

Published by
Infineon Technologies AG
85579 Neubiberg, Germany
© 2013-2016 Infineon Technologies AG All Rights Reserved.

## Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

## Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com/rfpower).

## Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

